

74ALVT16601

18-bit universal bus transceiver; 3-state

Rev. 03 — 5 July 2005

Product data sheet

1. General description

The 74ALVT16601 is a high-performance Bipolar Complementary Metal Oxide Semiconductor (BiCMOS) product designed for V_{CC} operation at 2.5 V and 3.3 V with I/O compatibility up to 5 V. This device is an 18-bit universal transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. Data flow in each direction is controlled by output enable (\overline{OEAB} and \overline{OEBA}), latch enable (LEAB and LEBA), and clock (CPAB and CPBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A-bus data is latched if CPAB is held at a HIGH or LOW level. If LEAB is LOW, the A-bus data is stored in the latch/flip-flop on the LOW-to-HIGH transition of CPAB. When \overline{OEAB} is LOW, the outputs are active. When \overline{OEAB} is HIGH, the outputs are in the high-impedance state. The clocks can be controlled with the clock enable inputs (\overline{CEAB} and \overline{CEBA}).

Data flow for B-to-A is similar to that of A-to-B but uses \overline{OEBA} , LEBA and CPBA.

Active bus hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

2. Features

- 18-bit bidirectional bus interface
- 5 V I/O compatible
- 3-state buffers
- Output capability: +64 mA and -32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion and extraction permitted
- Power-up reset
- Power-up 3-state
- No bus current loading when output is tied to 5 V bus
- Positive-edge triggered clock inputs
- Latch-up protection:
 - ◆ JESD78: exceeds 500 mA
- ESD protection:
 - ◆ MIL STD 883, method 3015: exceeds 2000 V
 - ◆ Machine model: exceeds 200 V

PHILIPS

3. Quick reference data

Table 1: Quick reference data

$GND = 0\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|--|---|-----|-----|-----|---------------|
| $V_{CC} = 2.5\text{ V}$ | | | | | | |
| t_{PLH} | propagation delay An to Bn or Bn to An | $C_L = 30\text{ pF}$ | - | 1.8 | - | ns |
| t_{PHL} | propagation delay An to Bn or Bn to An | $C_L = 30\text{ pF}$ | - | 2.2 | - | ns |
| C_i | input capacitance of control pins | $V_I = 0\text{ V}$ or V_{CC} | | 4 | - | pF |
| C_{io} | input/output capacitance of I/O pins | $V_{I/O} = 0\text{ V}$ or V_{CC} ; outputs disabled | | 8 | - | pF |
| I_{CC} | supply current | outputs disabled | - | 40 | - | μA |
| $V_{CC} = 3.3\text{ V}$ | | | | | | |
| t_{PLH} | propagation delay An to Bn or Bn to An | $C_L = 50\text{ pF}$ | - | 1.9 | - | ns |
| t_{PHL} | propagation delay An to Bn or Bn to An | $C_L = 50\text{ pF}$ | - | 2 | - | ns |
| C_i | input capacitance of control pins | $V_I = 0\text{ V}$ or V_{CC} | | 4 | - | pF |
| C_{io} | input/output capacitance of I/O pins | $V_{I/O} = 0\text{ V}$ or V_{CC} ; outputs disabled | | 8 | - | pF |
| I_{CC} | supply current | outputs disabled | - | 60 | - | μA |

4. Ordering information

Table 2: Ordering information

| Type number | Package | | | |
|----------------|-------------------|---------|--|----------|
| | Temperature range | Name | Description | Version |
| 74ALVT16601DL | -40 °C to +85 °C | SSOP56 | plastic shrink small outline package; 56 leads; body width 7.5 mm | SOT371-1 |
| 74ALVT16601DGG | -40 °C to +85 °C | TSSOP56 | plastic thin shrink small outline package; 56 leads; body width 6.1 mm | SOT364-1 |

5. Functional diagram

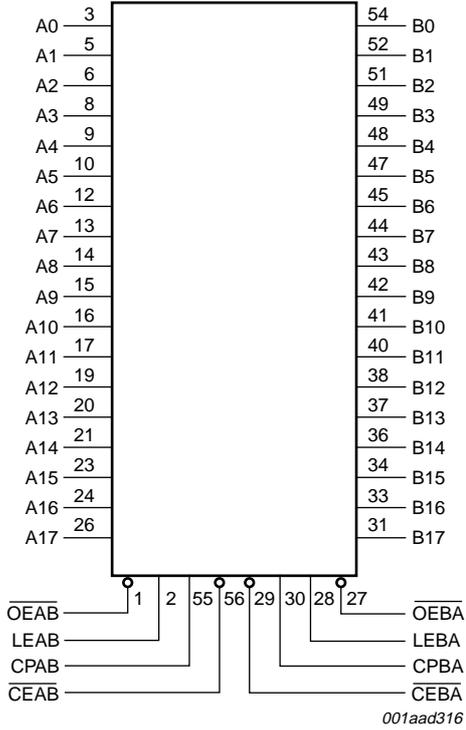


Fig 1. Logic symbol

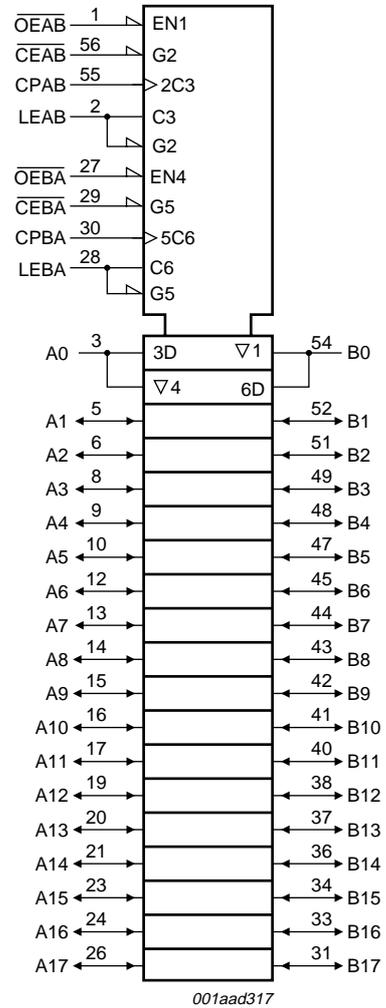


Fig 2. IEC logic symbol

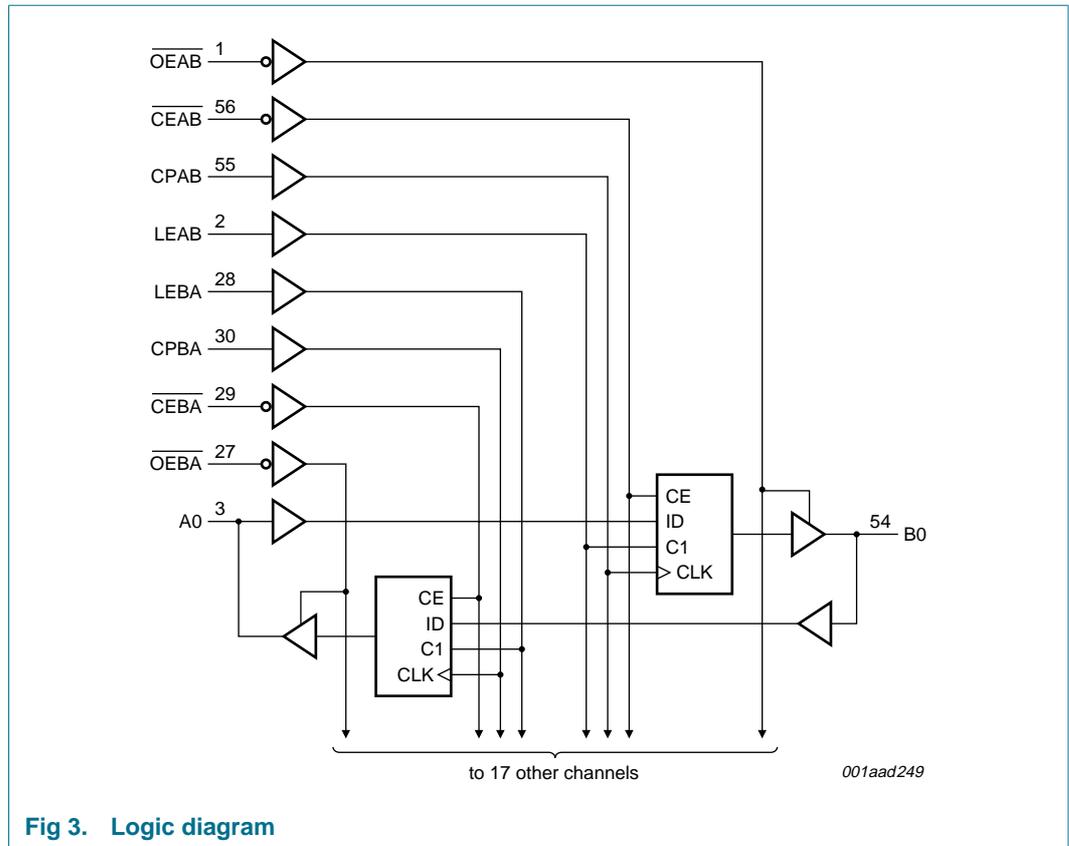
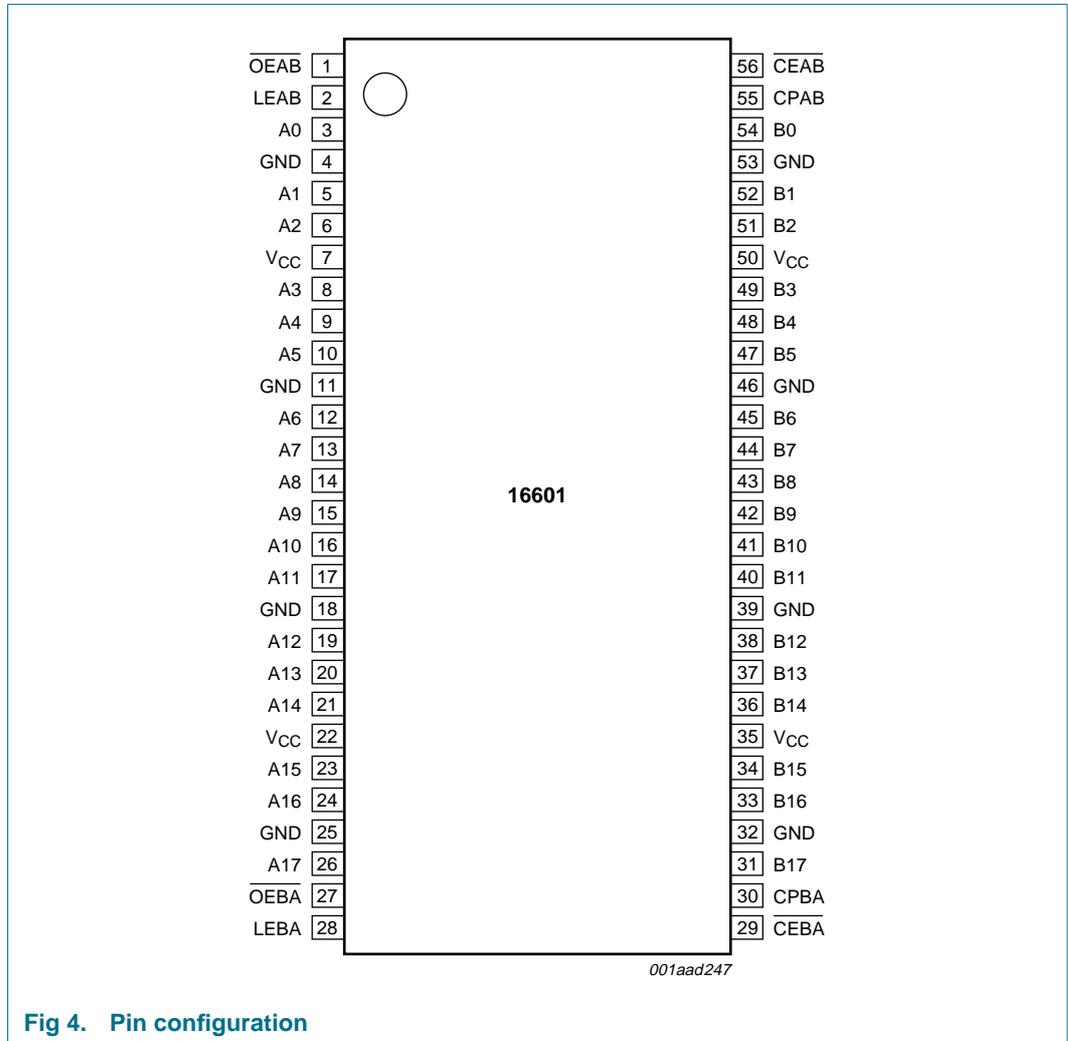


Fig 3. Logic diagram

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3: Pin description

| Symbol | Pin | Description |
|-----------------|-----|---|
| OEAB | 1 | A-to-B output enable input (active LOW) |
| LEAB | 2 | A-to-B latch enable input |
| A0 | 3 | data input or output (A side) |
| GND | 4 | ground (0 V) |
| A1 | 5 | data input or output (A side) |
| A2 | 6 | data input or output (A side) |
| V _{CC} | 7 | voltage supply |
| A3 | 8 | data input or output (A side) |

Table 3: Pin description ...continued

| Symbol | Pin | Description |
|--------------------------|-----|---|
| A4 | 9 | data input or output (A side) |
| A5 | 10 | data input or output (A side) |
| GND | 11 | ground (0 V) |
| A6 | 12 | data input or output (A side) |
| A7 | 13 | data input or output (A side) |
| A8 | 14 | data input or output (A side) |
| A9 | 15 | data input or output (A side) |
| A10 | 16 | data input or output (A side) |
| A11 | 17 | data input or output (A side) |
| GND | 18 | ground (0 V) |
| A12 | 19 | data input or output (A side) |
| A13 | 20 | data input or output (A side) |
| A14 | 21 | data input or output (A side) |
| V _{CC} | 22 | voltage supply |
| A15 | 23 | data input or output (A side) |
| A16 | 24 | data input or output (A side) |
| GND | 25 | ground (0 V) |
| A17 | 26 | data input or output (A side) |
| $\overline{\text{OEBA}}$ | 27 | B-to-A output enable input (active LOW) |
| LEBA | 28 | B-to-A latch enable input |
| $\overline{\text{CEBA}}$ | 29 | B-to-A clock enable (active LOW) |
| CPBA | 30 | B-to-A clock input (active rising edge) |
| B17 | 31 | data input or output (B side) |
| GND | 32 | ground (0 V) |
| B16 | 33 | data input or output (B side) |
| B15 | 34 | data input or output (B side) |
| V _{CC} | 35 | voltage supply |
| B14 | 36 | data input or output (B side) |
| B13 | 37 | data input or output (B side) |
| B12 | 38 | data input or output (B side) |
| GND | 39 | ground (0 V) |
| B11 | 40 | data input or output (B side) |
| B10 | 41 | data input or output (B side) |
| B9 | 42 | data input or output (B side) |
| B8 | 43 | data input or output (B side) |
| B7 | 44 | data input or output (B side) |
| B6 | 45 | data input or output (B side) |
| GND | 46 | ground (0 V) |
| B5 | 47 | data input or output (B side) |
| B4 | 48 | data input or output (B side) |
| B3 | 49 | data input or output (B side) |

Table 3: Pin description ...continued

| Symbol | Pin | Description |
|-----------------|-----|---|
| V _{CC} | 50 | voltage supply |
| B2 | 51 | data input or output (B side) |
| B1 | 52 | data input or output (B side) |
| GND | 53 | ground (0 V) |
| B0 | 54 | data input or output (B side) |
| CPAB | 55 | A-to-B clock input (active rising edge) |
| CEAB | 56 | A-to-B clock enable (active LOW) |

7. Functional description

7.1 Function table

Table 4: Function table [1]

| Control | | | | Input | Output |
|---------|------|------|------|----------------|----------------|
| CEAB | OEAB | LEAB | CPAB | A _n | B _n |
| CEBA | OEBA | LEBA | CPBA | B _n | A _n |
| X | H | X | X | X | Z |
| X | L | H | X | L | L |
| | | | | H | H |
| L | L | L | ↑ | L | L |
| | | | | H | H |
| L | L | L | H | X | Y [2] |
| | | | L | X | Y [3] |
| H | L | L | X | X | Y [2] |

- [1] H = HIGH voltage level;
 L = LOW voltage level;
 X = don't care;
 Z = high-impedance OFF-state;
 ↑ = LOW-to-HIGH clock transition

[2] Output level before the indicated steady-state input conditions were established.

[3] Output level before the indicated steady-state input conditions were established, provided that CPAB or CPBA was LOW before LEAB or LEBA went LOW.

8. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------|----------------|-----------------------------------|----------|------|------|
| V _{CC} | supply voltage | | -0.5 | +4.6 | V |
| V _I | input voltage | | [1] -0.5 | +7.0 | V |
| V _O | output voltage | output in OFF-state or HIGH-state | [1] -0.5 | +7.0 | V |

Table 5: Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|----------------------|----------------------|-------|------|------|
| I_{IK} | input diode current | $V_I < 0\text{ V}$ | - | -50 | mA |
| I_{OK} | output diode current | $V_O < 0\text{ V}$ | - | -50 | mA |
| I_O | output current | output in LOW-state | - | 128 | mA |
| | | output in HIGH-state | - | -64 | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| T_j | junction temperature | | [2] - | 150 | °C |

- [1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
- [2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

9. Recommended operating conditions

Table 6: Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|------------------------------------|---|-----|-----|-----|------|
| $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ | | | | | | |
| V_{CC} | supply voltage | | 2.3 | - | 2.7 | V |
| V_I | input voltage | | 0 | - | 5.5 | V |
| V_{IH} | HIGH-level input voltage | | 1.7 | - | - | V |
| V_{IL} | LOW-level input voltage | | - | - | 0.7 | V |
| I_{OH} | HIGH-level output current | | - | - | -8 | mA |
| I_{OL} | LOW-level output current | none | - | - | 8 | mA |
| | | current duty cycle $\leq 50\%$; $f \geq 1\text{ kHz}$ | - | - | 24 | mA |
| $\Delta t/\Delta V$ | input transition rise or fall rate | outputs enabled | - | - | 10 | ns/V |
| T_{amb} | ambient temperature | | -40 | - | +85 | °C |
| $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ | | | | | | |
| V_{CC} | supply voltage | | 3.0 | - | 3.6 | V |
| V_I | input voltage | | 0 | - | 5.5 | V |
| V_{IH} | HIGH-level input voltage | | 2.0 | - | - | V |
| V_{IL} | LOW-level input voltage | | - | - | 0.8 | V |
| I_{OH} | HIGH-level output current | | - | - | -32 | mA |
| I_{OL} | LOW-level output current | none | - | - | 32 | mA |
| | | current duty cycle $\leq 50\%$; $f \geq 1\text{ kHz}$ | - | - | 64 | mA |
| $\Delta t/\Delta V$ | input transition rise or fall rate | outputs enabled | - | - | 10 | ns/V |
| T_{amb} | ambient temperature | in free air | -40 | - | +85 | °C |

10. Static characteristics

Table 7: Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|---|--|----------------|----------|-----------|---------------|
| $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ [1] | | | | | | |
| V_{IK} | input diode voltage | $V_{CC} = 2.3\text{ V}$; $I_{IK} = -18\text{ mA}$ | - | -0.85 | -1.2 | V |
| V_{OH} | HIGH-level output voltage | $V_{CC} = 2.3\text{ V}$ to 3.6 V ; $I_{OH} = -100\text{ }\mu\text{A}$ | $V_{CC} - 0.2$ | - | - | V |
| | | $V_{CC} = 2.3\text{ V}$; $I_{OH} = -8\text{ mA}$ | 1.8 | - | - | V |
| V_{OL} | LOW-level output voltage | $V_{CC} = 2.3\text{ V}$; $I_{OL} = 100\text{ }\mu\text{A}$ | - | 0.07 | 0.2 | V |
| | | $V_{CC} = 2.3\text{ V}$; $I_{OL} = 24\text{ mA}$ | - | 0.3 | 0.5 | V |
| | | $V_{CC} = 2.3\text{ V}$; $I_{OL} = 8\text{ mA}$ | - | - | 0.4 | V |
| V_{RST} | power-up LOW-state output voltage | $V_{CC} = 2.7\text{ V}$; $I_O = 1\text{ mA}$; $V_I = V_{CC}$ or GND | [2] - | - | 0.55 | V |
| I_{LI} | input leakage current control pins | $V_{CC} = 2.7\text{ V}$; $V_I = V_{CC}$ or GND | - | 0.1 | ± 1 | μA |
| | | $V_{CC} = 0\text{ V}$ or 2.7 V ; $V_I = 5.5\text{ V}$ | - | 0.1 | 10 | μA |
| | I/O data pins | $V_{CC} = 0\text{ V}$ or 2.7 V ; $V_I = 5.5\text{ V}$ | [3] - | 0.1 | 20 | μA |
| | | $V_{CC} = 2.7\text{ V}$; $V_I = V_{CC}$ | [3] - | 0.1 | 10 | μA |
| | | $V_{CC} = 2.7\text{ V}$; $V_I = 0\text{ V}$ | [3] - | +0.1 | -5 | μA |
| I_{OFF} | power-down leakage current | $V_{CC} = 0\text{ V}$; V_I or $V_O = 0\text{ V}$ to 4.5 V | - | 0.1 | ± 100 | μA |
| I_{HOLD} | bus hold current data inputs | $V_{CC} = 2.3\text{ V}$; $V_I = 0.7\text{ V}$ | [4] - | 90 | - | μA |
| | | $V_{CC} = 2.3\text{ V}$; $V_I = 1.7\text{ V}$ | [4] - | -75 | - | μA |
| I_{EX} | external current into output | output in HIGH-state when $V_O > V_{CC}$; $V_O = 5.5\text{ V}$; $V_{CC} = 2.3\text{ V}$ | - | 10 | 125 | μA |
| I_{PU}, I_{PD} | power-up/down 3-state output current | $V_{CC} \leq 1.2\text{ V}$; $V_O = 0.5\text{ V}$ to V_{CC} ; $V_I = \text{GND}$ or V_{CC} ; $\overline{\text{OEAB}}$ or $\overline{\text{OEAB}}$ don't care | [5] - | 1 | 100 | μA |
| I_{CC} | supply current | $V_{CC} = 2.7\text{ V}$; $V_I = \text{GND}$ or V_{CC} ; $I_O = 0\text{ A}$ | - | - | - | - |
| | | outputs HIGH-state | - | 0.04 | 0.1 | mA |
| | | outputs LOW-state | - | 2.5 | 4.5 | mA |
| ΔI_{CC} | additional supply current per input pin | outputs disabled | [6] - | 0.04 | 0.1 | mA |
| | | $V_{CC} = 2.3\text{ V}$ to 2.7 V ; one input at $V_{CC} - 0.6\text{ V}$, other inputs at V_{CC} or GND | [7] - | 0.01 | 0.4 | mA |
| | | $V_{CC} = 2.3\text{ V}$; $V_I = 0\text{ V}$ or V_{CC} | - | 4 | - | pF |
| C_{iO} | input/output capacitance of I/O pins | $V_{I/O} = 0\text{ V}$ or V_{CC} ; outputs disabled | - | 8 | - | pF |
| $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ [8] | | | | | | |
| V_{IK} | input diode voltage | $V_{CC} = 3.0\text{ V}$; $I_{IK} = -18\text{ mA}$ | - | -0.85 | -1.2 | V |
| V_{OH} | HIGH-level output voltage | $V_{CC} = 3.0\text{ V}$ to 3.6 V ; $I_{OH} = -100\text{ }\mu\text{A}$ | $V_{CC} - 0.2$ | V_{CC} | - | V |
| | | $V_{CC} = 3.0\text{ V}$; $I_{OH} = -32\text{ mA}$ | 2.0 | 2.3 | - | V |

Table 7: Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

 $T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|-----------------------------------|---|--|------|------|------|------|----|
| V _{OL} | LOW-level output voltage | V _{CC} = 3.0 V; I _{OL} = 100 μA | - | 0.07 | 0.2 | V | |
| | | V _{CC} = 3.0 V; I _{OL} = 16 mA | - | 0.25 | 0.4 | V | |
| | | V _{CC} = 3.0 V; I _{OL} = 32 mA | - | 0.3 | 0.5 | V | |
| | | V _{CC} = 3.0 V; I _{OL} = 64 mA | - | 0.4 | 0.55 | V | |
| V _{RST} | power-up LOW-state output voltage | V _{CC} = 2.7 V; I _O = 1 mA; V _I = V _{CC} or GND | [2] | - | 0.55 | V | |
| I _{LI} | input leakage current control pins | V _{CC} = 3.6 V; V _I = V _{CC} or GND | - | 0.1 | ±1 | μA | |
| | | V _{CC} = 0 V or 3.6 V; V _I = 5.5 V | - | 0.1 | 10 | μA | |
| | I/O data pins | V _{CC} = 3.6 V; V _I = 5.5 V | [3] | - | 0.1 | 20 | μA |
| | | V _{CC} = 3.6 V; V _I = V _{CC} | [3] | - | 0.5 | 10 | μA |
| | | V _{CC} = 3.6 V; V _I = 0 V | [3] | - | +0.1 | -5 | μA |
| I _{OFF} | power-down leakage current | V _{CC} = 0 V; V _I or V _O = 0 V to 4.5 V | - | 0.1 | ±100 | μA | |
| I _{HOLD} | bus hold current data inputs | V _{CC} = 3 V; V _I = 0.8 V | [9] | 75 | 130 | - | μA |
| | | V _{CC} = 3 V; V _I = 2.0 V | [9] | -75 | -140 | - | μA |
| | | V _{CC} = 0 V to 3.6 V; V _{CC} = 3.6 V | [9] | ±500 | - | - | μA |
| I _{EX} | external current into output | output in HIGH-state when V _O > V _{CC} ; V _O = 5.5 V; V _{CC} = 2.3 V | - | 10 | 125 | μA | |
| I _{PU} , I _{PD} | power-up/down 3-state output current | V _{CC} ≤ 1.2 V; V _O = 0.5 V to V _{CC} ; V _I = GND or V _{CC} ; $\overline{\text{OEAB}}$ or $\overline{\text{OEAB}}$ don't care | [10] | - | 1 | ±100 | μA |
| I _{CC} | supply current | V _{CC} = 3.6 V; V _I = GND or V _{CC} ; I _O = 0 A | | | | | |
| | | outputs HIGH-state | - | 0.06 | 0.1 | mA | |
| | | outputs LOW-state | - | 3.5 | 5 | mA | |
| | | outputs disabled | [6] | - | 0.06 | 0.1 | mA |
| ΔI _{CC} | additional supply current per input pin | V _{CC} = 3 V to 3.6 V; one input at V _{CC} - 0.6 V, other inputs at V _{CC} or GND | [7] | - | 0.04 | 0.4 | mA |
| C _i | input capacitance of control pins | V _I = 0 V or V _{CC} | | 4 | - | pF | |
| C _{IO} | input/output capacitance of I/O pins | V _{I/O} = 0 V or V _{CC} ; outputs disabled | | 8 | - | pF | |

[1] All typical values are at V_{CC} = 2.5 V and T_{amb} = 25 °C.

[2] For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.

[3] Unused pins at V_{CC} or GND.

[4] Not guaranteed.

[5] This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms. From V_{CC} = 1.2 V to V_{CC} = 2.5 V ± 0.2 V a transition time of 100 μs is permitted. This parameter is valid for T_{amb} = 25 °C only.[6] I_{CC} is measured with outputs pulled up to V_{CC} or pulled down to ground.[7] This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.[8] All typical values are at V_{CC} = 3.3 V and T_{amb} = 25 °C.

[9] This is the bus hold overdrive current required to force the input to the opposite logic state.

[10] This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms. From V_{CC} = 1.2 V to V_{CC} = 3.3 V ± 0.3 V a transition time of 100 μs is permitted. This parameter is valid for T_{amb} = 25 °C only.

11. Dynamic characteristics

Table 8: Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 11](#).

$T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|--|-------------------------------|------|------|-----|------|
| $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ [1]; $C_L = 30\text{ pF}$ | | | | | | |
| t_{PHL} | propagation delay | | | | | |
| | An to Bn or Bn to An | see Figure 5 | 1.4 | 2.2 | 3.5 | ns |
| | LEAB to Bn or LEBA to An | see Figure 6 | 1.5 | 2.5 | 4.0 | ns |
| | CPAB to Bn or CPBA to An | see Figure 7 | 1.9 | 3.2 | 5.2 | ns |
| t_{PLH} | propagation delay | | | | | |
| | An to Bn or Bn to An | see Figure 5 | 1.0 | 1.8 | 3.0 | ns |
| | LEAB to Bn or LEBA to An | see Figure 6 | 1.5 | 2.5 | 4.0 | ns |
| | CPAB to Bn or CPBA to An | see Figure 7 | 2.2 | 3.5 | 5.0 | ns |
| t_{PHZ} | output disable time from HIGH-level | see Figure 9 | 2.2 | 3.1 | 4.4 | ns |
| t_{PLZ} | output disable time from LOW-level | see Figure 10 | 1.6 | 2.3 | 3.4 | ns |
| t_{PZH} | output enable time to HIGH-level | see Figure 9 | 2.3 | 3.6 | 4.8 | ns |
| t_{PZL} | output enable time to LOW-level | see Figure 10 | 1.9 | 2.9 | 4.4 | ns |
| $t_{h(H)}$ | hold time HIGH | | | | | |
| | An to CPAB or Bn to CPBA | see Figure 8 | 0.0 | -1.1 | - | ns |
| | An to LEAB or Bn to LEAB | see Figure 8 | 1.5 | 0.4 | - | ns |
| | \overline{CEAB} to CPAB or \overline{CEBA} to CPBA | see Figure 8 | 2.0 | 0.4 | - | ns |
| $t_{h(L)}$ | hold time LOW | | | | | |
| | An to CPAB or Bn to CPBA | see Figure 8 | 0.0 | -0.3 | - | ns |
| | An to LEAB or Bn to LEAB | see Figure 8 | 1.9 | 1.0 | - | ns |
| | \overline{CEAB} to CPAB or \overline{CEBA} to CPBA | see Figure 8 | +0.8 | -0.1 | - | ns |
| $t_{su(H)}$ | set-up time HIGH | | | | | |
| | An to CPAB or Bn to CPBA | see Figure 8 | 2.0 | 0.4 | - | ns |
| | An to LEAB or Bn to LEBA | see Figure 8 | 0.0 | -1.0 | - | ns |
| | \overline{CEAB} to CPAB or \overline{CEBA} to CPBA | see Figure 8 | 0.7 | 0.3 | - | ns |
| $t_{su(L)}$ | set-up time LOW | | | | | |
| | An to CPAB or Bn to CPBA | see Figure 8 | 2.0 | 1.2 | - | ns |
| | An to LEAB or Bn to LEBA | see Figure 8 | 1.5 | 0.4 | - | ns |
| | \overline{CEAB} to CPAB or \overline{CEBA} to CPBA | see Figure 8 | +0.3 | -0.4 | - | ns |
| t_{WH} | pulse width HIGH | | | | | |
| | CPAB or CPBA | see Figure 7 | 3.0 | - | - | ns |
| | LEAB or LEBA | see Figure 6 | 1.5 | - | - | ns |
| t_{WL} | pulse width LOW | | | | | |
| | CPAB or CPBA | see Figure 7 | 3.0 | - | - | ns |

Table 8: Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 11](#).

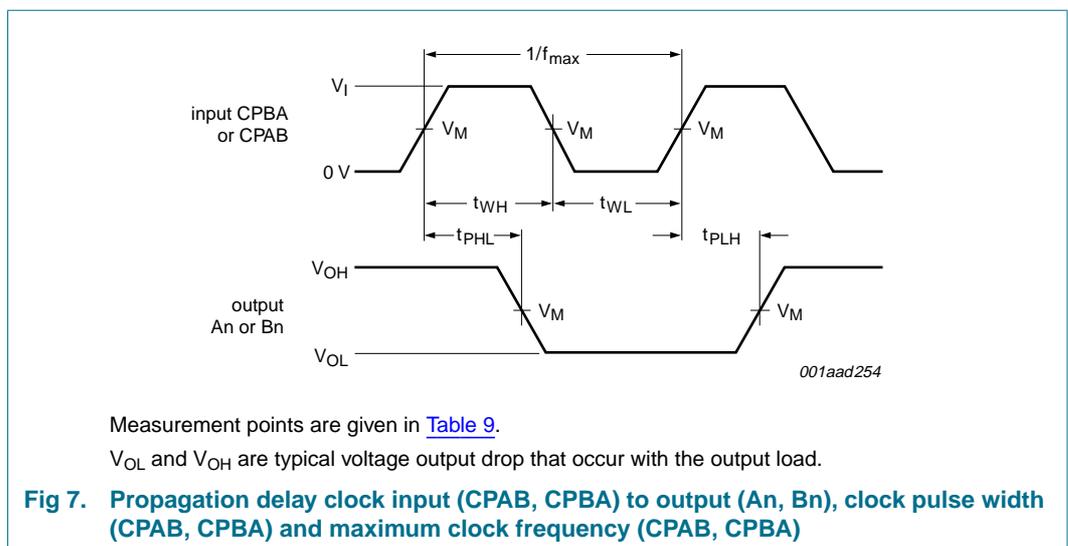
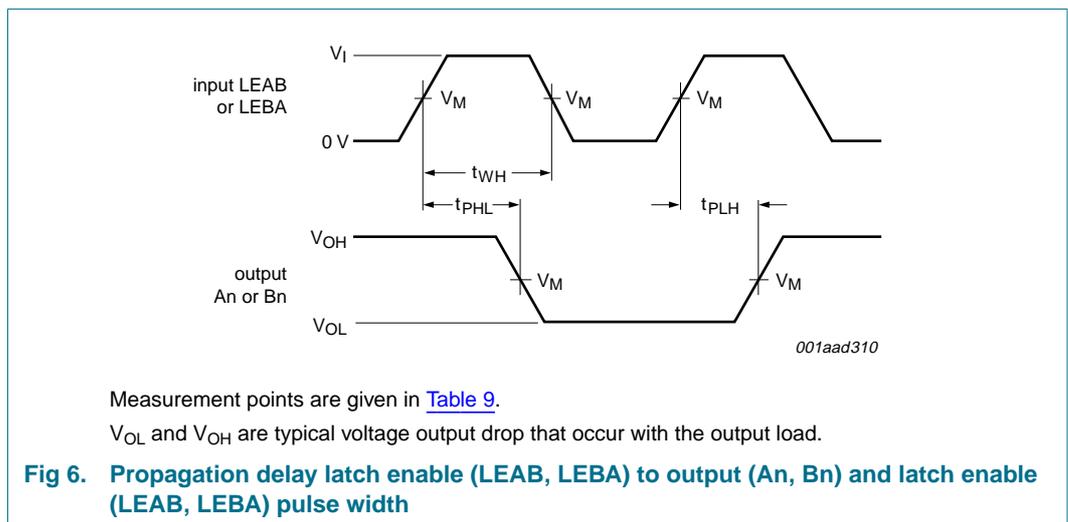
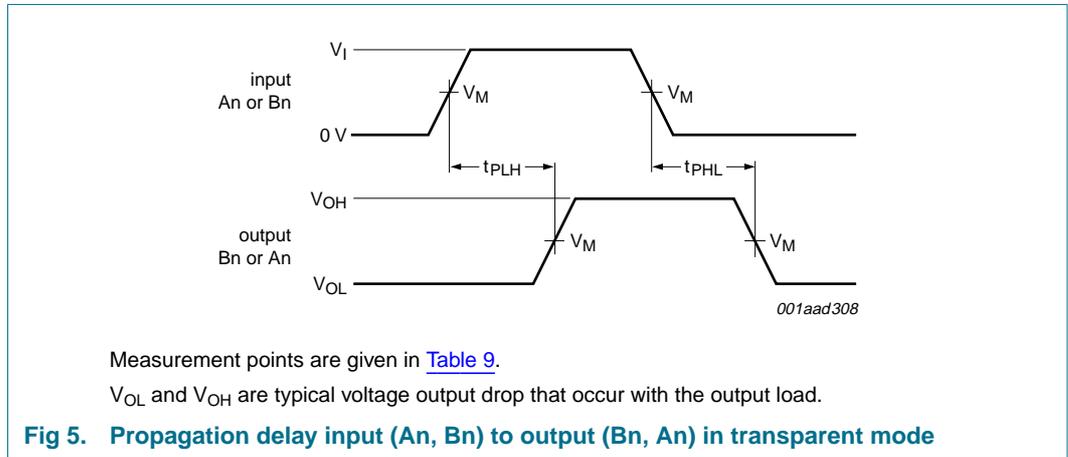
$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|--|-------------------------------|------|------|-----|------|
| $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ [2]; $C_L = 50\text{ pF}$ | | | | | | |
| t_{PHL} | propagation delay | | | | | |
| | An to Bn or Bn to An | see Figure 5 | 1.1 | 2.0 | 2.8 | ns |
| | LEAB to Bn or LEBA to An | see Figure 6 | 1.4 | 2.3 | 3.6 | ns |
| | CPAB to Bn or CPBA to An | see Figure 7 | 1.7 | 2.7 | 4.1 | ns |
| t_{PLH} | propagation delay | | | | | |
| | An to Bn or Bn to An | see Figure 5 | 1.2 | 1.9 | 2.9 | ns |
| | LEAB to Bn or LEBA to An | see Figure 6 | 1.5 | 2.5 | 3.8 | ns |
| | CPAB to Bn or CPBA to An | see Figure 7 | 2.1 | 3.1 | 4.5 | ns |
| t_{PHZ} | output disable time from HIGH-level | see Figure 9 | 2.7 | 3.6 | 4.9 | ns |
| t_{PLZ} | output disable time from LOW-level | see Figure 10 | 2.1 | 2.8 | 4 | ns |
| t_{PZH} | output enable time to HIGH-level | see Figure 9 | 2.2 | 3.2 | 4.2 | ns |
| t_{PZL} | output enable time to LOW-level | see Figure 10 | 1.6 | 2.5 | 3.8 | ns |
| $t_{h(H)}$ | hold time HIGH | | | | | |
| | An to CPAB or Bn to CPBA | see Figure 8 | +1.0 | -0.5 | - | ns |
| | An to LEAB or Bn to LEAB | see Figure 8 | 1.5 | 0.1 | - | ns |
| | \overline{CEAB} to CPAB or \overline{CEBA} to CPBA | see Figure 8 | 1.5 | 0.7 | - | ns |
| $t_{h(L)}$ | hold time LOW | | | | | |
| | An to CPAB or Bn to CPBA | see Figure 8 | +1.0 | -0.3 | - | ns |
| | An to LEAB or Bn to LEAB | see Figure 8 | 1.5 | 0.5 | - | ns |
| | \overline{CEAB} to CPAB or \overline{CEBA} to CPBA | see Figure 8 | +1.0 | -0.3 | - | ns |
| $t_{su(H)}$ | set-up time HIGH | | | | | |
| | An to CPAB or Bn to CPBA | see Figure 8 | 1.5 | 0.4 | - | ns |
| | An to LEAB or Bn to LEBA | see Figure 8 | +1.0 | -0.5 | - | ns |
| | \overline{CEAB} to CPAB or \overline{CEBA} to CPBA | see Figure 8 | 1.5 | 0.3 | - | ns |
| $t_{su(L)}$ | set-up time LOW | | | | | |
| | An to CPAB or Bn to CPBA | see Figure 8 | 1.5 | 0.6 | - | ns |
| | An to LEAB or Bn to LEBA | see Figure 8 | +1.0 | -0.1 | - | ns |
| | \overline{CEAB} to CPAB or \overline{CEBA} to CPBA | see Figure 8 | 1.0 | -0.4 | - | ns |
| t_{WH} | pulse width HIGH | | | | | |
| | CPAB or CPBA | see Figure 7 | 2.0 | - | - | ns |
| | LEAB or LEBA | see Figure 6 | 1.5 | - | - | ns |
| t_{WL} | pulse width LOW | | | | | |
| CPAB or CPBA | see Figure 7 | 2.0 | - | - | ns | |

[1] All typical values are measured at $V_{CC} = 2.5\text{ V}$ and $T_{amb} = 25\text{ }^{\circ}\text{C}$.

[2] All typical values are measured at $V_{CC} = 3.3\text{ V}$ and $T_{amb} = 25\text{ }^{\circ}\text{C}$.

12. Waveforms



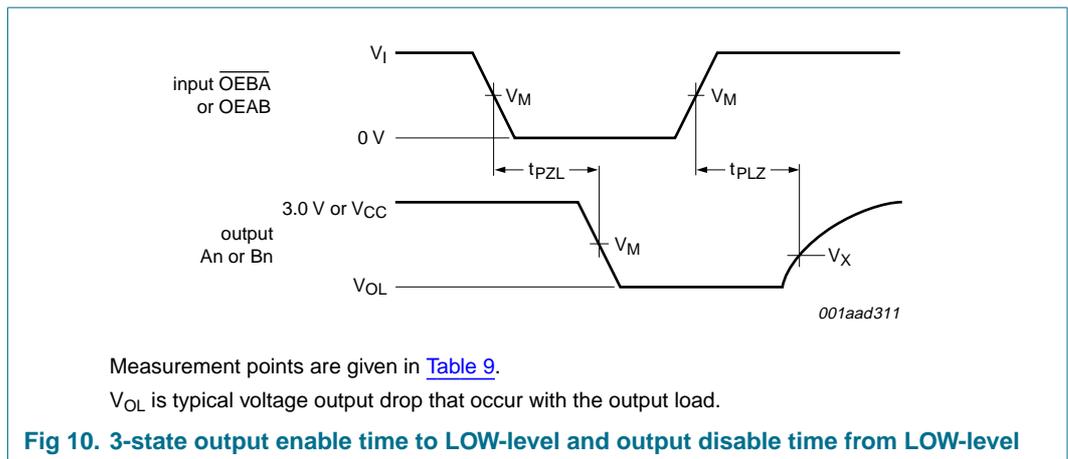
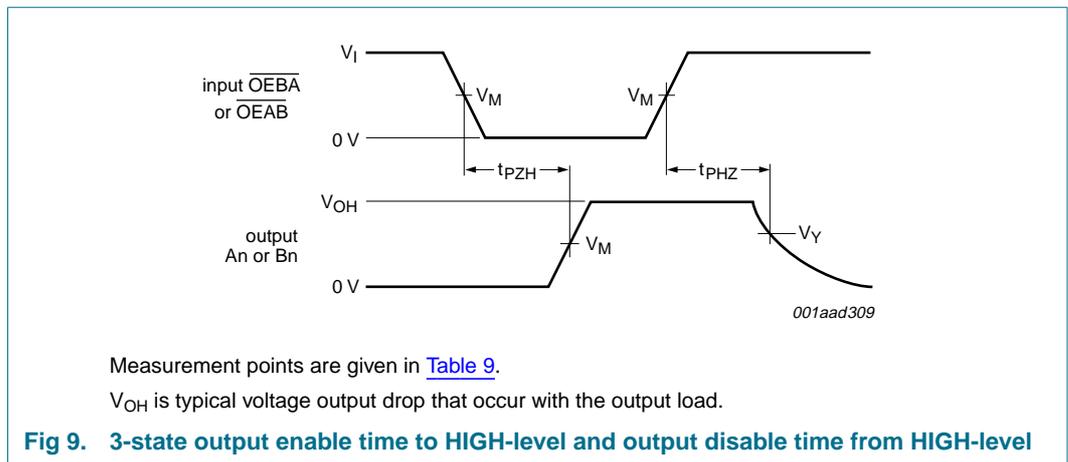
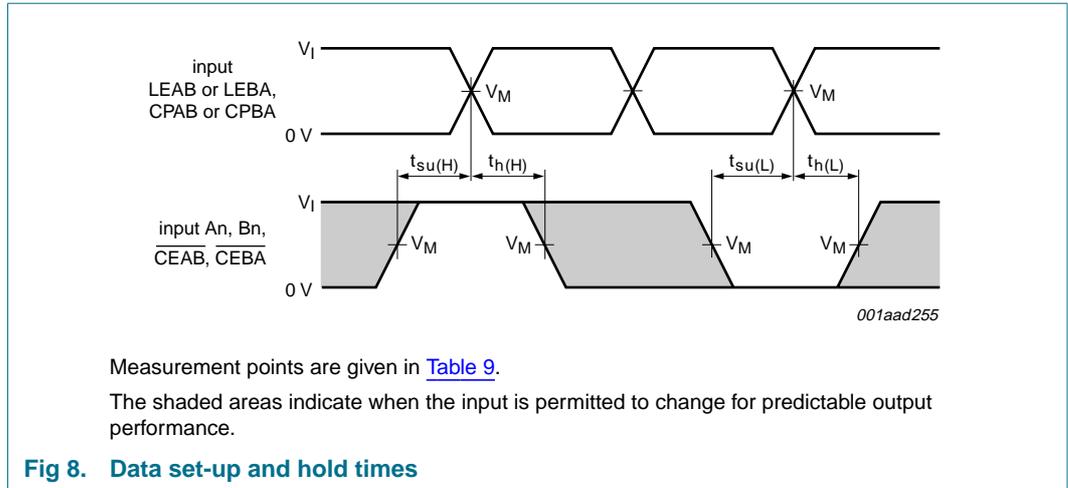
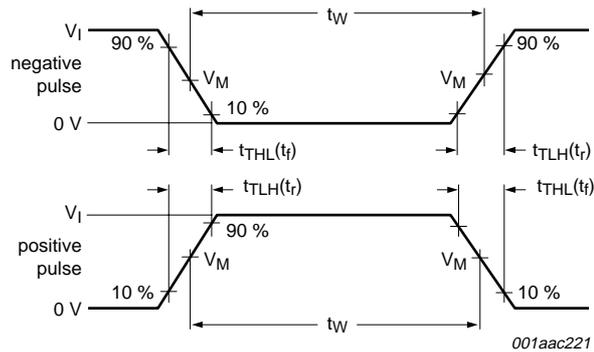


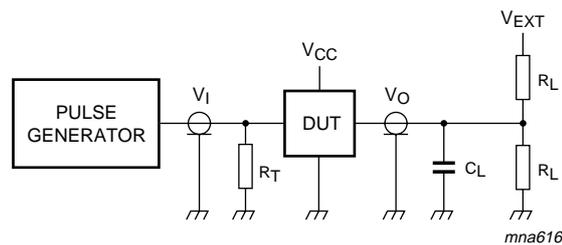
Table 9: Measurement points

| Supply voltage | Input | Output | | |
|---------------------|---------------------|---------------------|--------------------------|--------------------------|
| | V_M | V_M | V_X | V_Y |
| $\geq 3\text{ V}$ | 1.5 V | 1.5 V | $V_{OL} + 0.3\text{ V}$ | $V_{OH} - 0.3\text{ V}$ |
| $\leq 2.7\text{ V}$ | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ | $V_{OL} + 0.15\text{ V}$ | $V_{OH} - 0.15\text{ V}$ |



Measurement points are given in Table 9.

a. Input pulse definition



Test data is given in Table 10.

Definitions test circuit:

R_L = Load resistor.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

V_{EXT} = Test voltage for switching times.

b. Test circuit

Fig 11. Load circuitry for switching times

Table 10: Test data

| Input | | | | Load | | V_{EXT} | | | |
|-------------------------------------|----------------------|--------|----------------------|----------------|--------------|--------------------------|--------------------|--------------------|--|
| V_I | f_i | t_w | t_r, t_f | C_L | R_L | t_{PLZ}, t_{PZL} | t_{PLH}, t_{PHL} | t_{PHZ}, t_{PZH} | |
| 3.0 V or V_{CC} whichever is less | $\leq 10\text{ MHz}$ | 500 ns | $\leq 2.5\text{ ns}$ | 30 pF or 50 pF | 500 Ω | 6 V or $2 \times V_{CC}$ | open | GND | |

13. Package outline

SSOP56: plastic shrink small outline package; 56 leads; body width 7.5 mm

SOT371-1

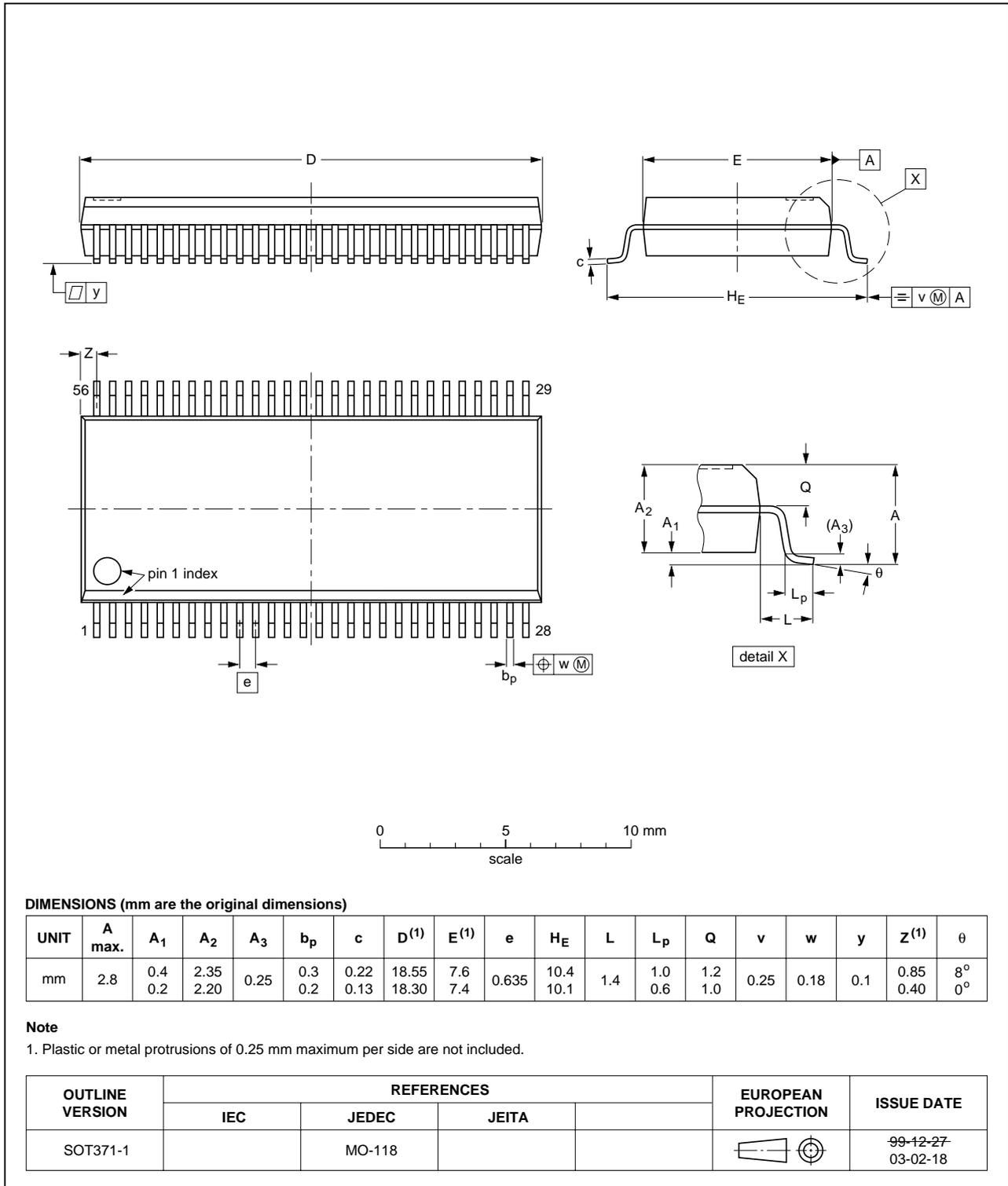


Fig 12. Package outline SOT371-1 (SSOP56)

TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1 mm

SOT364-1

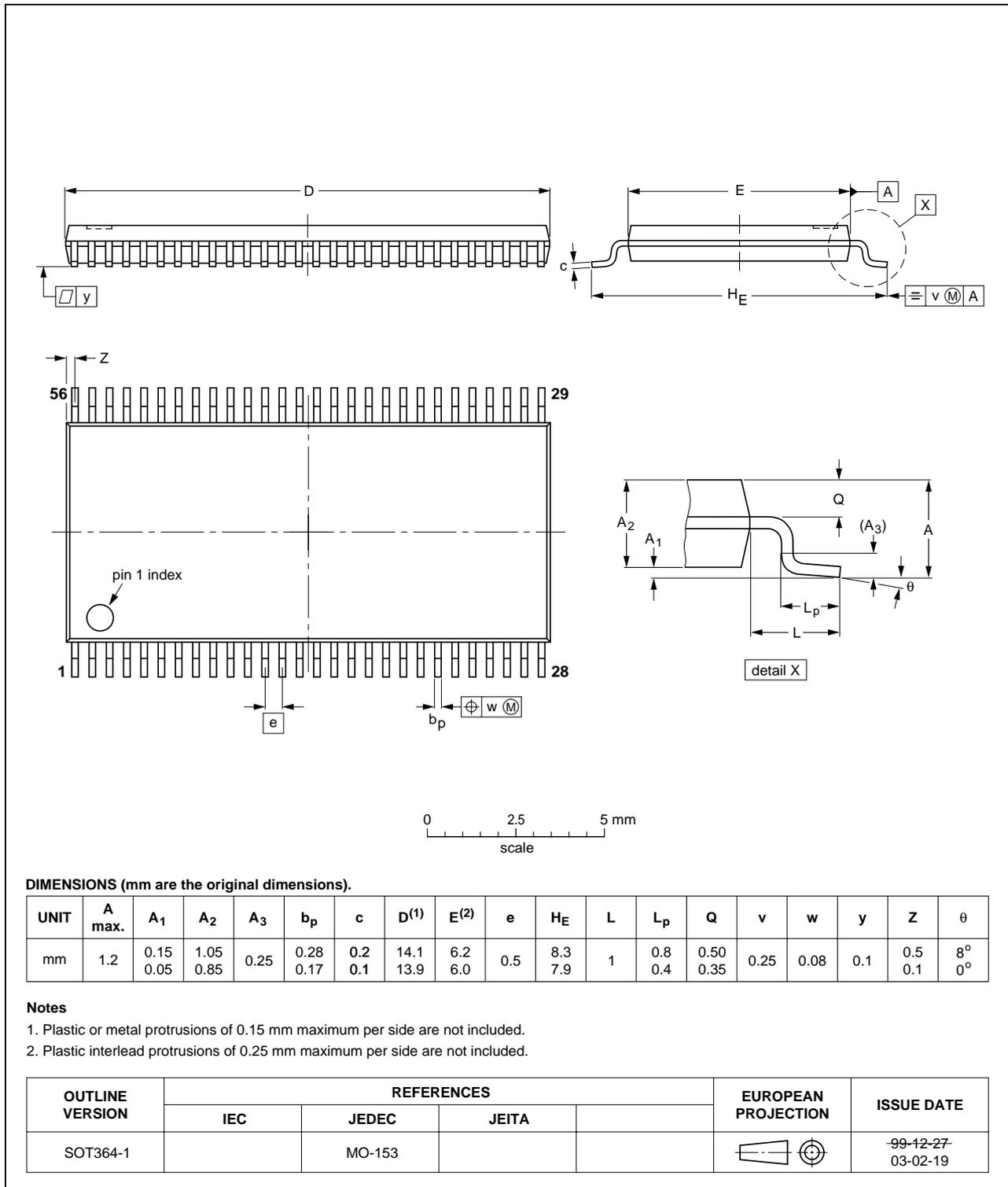


Fig 13. Package outline SOT364-1 (TSSOP56)

14. Revision history

Table 11: Revision history

| Document ID | Release date | Data sheet status | Change notice | Doc. number | Supersedes |
|----------------|--------------|-----------------------|---------------|----------------|---|
| 74ALVT16601_3 | 20050705 | Product data sheet | - | - | 74ALVT16601_2 |
| Modifications: | | | | | |
| | | | | | <ul style="list-style-type: none">• The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors.• Section 2 “Features”: modified ‘JEDEC Std 17’ into ‘JESD78’.• Table 8 “Dynamic characteristics”: changed values of propagation delay, output enable and output disable time. |
| 74ALVT16601_2 | 19980213 | Product specification | - | 9397 750 03571 | 74ALVT16601_1 |
| 74ALVT16601_1 | - | - | - | - | - |

15. Data sheet status

| Level | Data sheet status ^[1] | Product status ^{[2] [3]} | Definition |
|-------|----------------------------------|-----------------------------------|--|
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| III | Product data | Production | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). |

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[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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